

**Low-Power Mode Supply Currents (Into  $V_{CC}$ ) Excluding External Current**

 over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)<sup>(1) (2)</sup>

PARAMETER	$V_{CC}$	PMMCOREVx	-40°C		25°C		60°C		85°C		UNIT
			TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
$I_{LPM0,1MHz}$ Low-power mode 0 <sup>(3)(4)</sup>	2.2 V	0		73	77	85	80		85	97	$\mu A$
	3.0 V	3		79	83	92	88		95	105	
$I_{LPM2}$ Low-power mode 2 <sup>(5)(4)</sup>	2.2 V	0		6.5	6.5	12	10		11	17	$\mu A$
	3.0 V	3		7.0	7.0	13	11		12	18	
$I_{LPM3,XT1LF}$ Low-power mode 3, crystal mode <sup>(6)(4)</sup>	2.2 V	0		1.60	1.90		2.6		5.6		$\mu A$
		1		1.65	2.00		2.7		5.9		
		2		1.75	2.15		2.9		6.1		
	3.0 V	0		1.8	2.1	2.9	2.8		5.8	8.3	
		1		1.9	2.3		2.9		6.1		
		2		2.0	2.4	3.9	3.1		6.4	9.3	
$I_{LPM3,VLO}$ Low-power mode 3, VLO mode <sup>(7)(4)</sup>	3.0 V	0		1.1	1.4	2.7	1.9		4.9	7.4	$\mu A$
		1		1.1	1.4		2.0		5.2		
		2		1.2	1.5		2.1		5.3		
		3		1.3	1.6	3.0	2.2		5.4	8.5	
$I_{LPM4}$ Low-power mode 4 <sup>(8)(4)</sup>	3.0 V	0		0.9	1.1	1.5	1.8		4.8	7.3	$\mu A$
		1		1.1	1.2		2.0		5.1		
		2		1.2	1.2		2.1		5.2		
		3		1.3	1.3	1.6	2.2		5.3	8.1	
$I_{LPM4.5}$ Low-power mode 4.5 <sup>(9)</sup>	3.0 V			0.15	0.18	0.35	0.26		0.5	1.0	$\mu A$

**Electrical Characteristics**
**Active Mode Supply Current Into  $V_{CC}$  Excluding External Current**

 over recommended operating free-air temperature (unless otherwise noted)<sup>(1) (2) (3)</sup>

PARAMETER	EXECUTION MEMORY	$V_{CC}$	PMMCOREVx	FREQUENCY ( $f_{DCO} = f_{MCLK} = f_{SMCLK}$ )										UNIT
				1 MHz		8 MHz		12 MHz		20 MHz		25 MHz		
				TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	
$I_{AM, Flash}$	Flash	3.0 V	0	0.36	0.47	2.32	2.60						$mA$	
			1	0.40		2.65		4.0	4.4					
			2	0.44		2.90		4.3		7.1	7.7			
			3	0.46		3.10		4.6		7.6		10.1 11.0		
$I_{AM, RAM}$	RAM	3.0 V	0	0.20	0.24	1.20	1.30						$mA$	
			1	0.22		1.35		2.0	2.2					
			2	0.24		1.50		2.2		3.7	4.2			
			3	0.26		1.60		2.4		3.9		5.3 6.2		

 (1) All inputs are tied to 0 V or to  $V_{CC}$ . Outputs do not source or sink any current.

(2) The currents are characterized with a Micro Crystal MS1V-T1K crystal with a load capacitance of 12.5 pF. The internal and external load capacitance are chosen to closely match the required 12.5 pF.

 (3) Characterized with program executing typical data processing. USB disabled ( $V_{USBEN} = 0$ ,  $SLDOEN = 0$ ).

 $f_{ACLK} = 32786$  Hz,  $f_{DCO} = f_{MCLK} = f_{SMCLK}$  at specified frequency.

 $XTS = CPUOFF = SCG0 = SCG1 = OSCOFF = SMCLKOFF = 0$ .